

Micro Commercial Components

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Features

- For general purpose applications
- These diodes are also available in the DO-35 case with type designation 1N5711 and 1N6263, in the Micro-MELF case with type designation MCL5711 and MCL6263.
- Lead Free Finish/RoHS Compliant(Note 1) ("P" Suffix designates Compliant. See ordering information)

Maximum Ratings

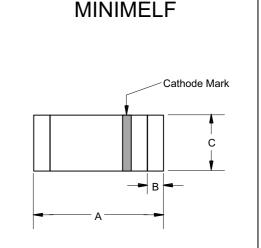
| Repetitive Peak Reverse | | | |
|------------------------------|------------------|-------------------------|---|
| Voltage | V _R | | |
| DL5711 | | 70V | |
| DL6263 | | 60V | |
| Maximum Forward | | 2.0A | tp<10uS, T _A =25 ^o C |
| Surge Current | IFSM | 2.0A | T _A =25 ^o C |
| Power Dissipation | Ρτοτ | 400mW* | |
| Junction Temperature | ΤJ | 125 ⁰ C | |
| Storage Temperature Range | T _{STG} | -55~+150 ⁰ C | |

* Valid provided that electrodes are kept at ambient temperature

Small Signal Schottky Diodes

DL5711

DL6263



DIMENSION

SUGGESTED SOLDER PAD LAYOUT

MM

MAX

3.60

0.40

1.50

0.030"

MIN

3.40

0.20

1.40

INCHES

MIN

.134

.008

.055

MAX

.142

.016

.059

0.075"

DIM

A

В

С

Electrical Characteristics @ 25°C Unless Otherwise Specified

| Maximum Forward Voltage | V _F | 0.41V 1.0V | I _F = 1.0mA I _F = 15mA |
|--|------------------|---------------|--|
| Minimum Reverse Breakdown voltage DL5711 DL6263 | V _R | 70V 60V | |
| Maximum Leakage current | I _R | 200nA | V _R =50V |
| Maximum Junction Capacitance | CJ | 2.0pF | V _R =0, f=1MHz |
| Maximum Reverse recovery time | t _{rr} | 1.0ns | I _F =5.0mA , I _R =5.0mA , |
| Maximum Thermal resistance junction to Ambient Air | R _{ŧJA} | 0.3K/ W | |

Note:1.Lead in Glass Exemption Applied, see EU Directive Annex 5.

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NOTE

DL5711,DL6263



Fig. I Typical variation of fwd. current vs forward. voltage for primary conduction through the Schottky barrier

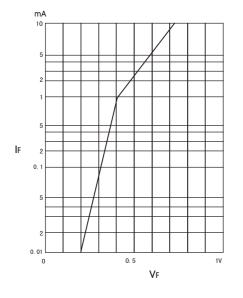


Fig.3 Typical variation of reverse current at various temperatures

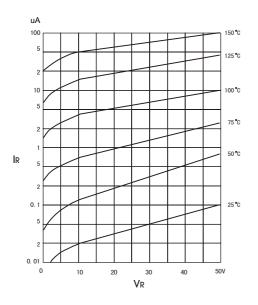


Fig.2 Typical forward conduction curve of combination Schottky barrier and PN junction guard ring

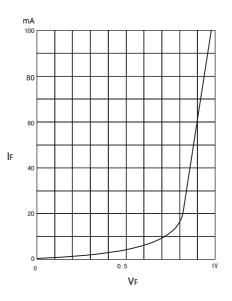
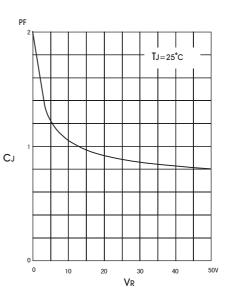


Fig.4 Typical capacitance curve as a function of reverse voltage



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Ordering Information

| Device | Packing |
|------------------|-----------------------|
| (Part Number)-TP | Tape&Reel2.5Kpcs/Reel |

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